## NSN 5962-01-502-9877

Memory Microcircuit - Page 1 of 1



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| Maximum Power Dissipation Rating:  |
|--|
| 1.0 watts  |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| Storage Tempurature Range:   |
| -65.0/+150.0 degrees celsius   |
| End Application:   |
| F-16 aircraft  |
| Features Provided:   |
| Electrostatic sensitive and monolithic   |
| Inclosure Material:  |
| Glass and ceramic  |
| Inclosure Configuration:   |
| Dual-in-line   |
| Product Name:  |
| Microcircuit, memory, digital, cmos 8k x 8-bit prom, monolithic silicon  |
| Voltage Rating And Type Per Characteristic:  |
| -0.5 volts input and 7.0 volts input   |
| Time Rating Per Chacteristic:  |
| 35.00 nanoseconds af output megawatts  |
| Memory Device Type:  |
| Prom   |
| Special Features:  |
| Generic p/n 7c261  |
| Test Data Document:  |
| $96906 \hbox{-mil-std-883 standard (includes industry or association standards, \ individual \ manufactureer \ standards, \ etc.)}.$ |
| Terminal Type And Quantity:  |
| 24 printed circuit   |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
| <del></del>  |
| Demilitarization:  |
| Yes - demil/mli  |
| Fiig:  |
| A458a0   |
|  |